<u>MOSFET</u> - P-Channel, PowerTrench[®], Logic Level

-40 V, -25 A, 21 m Ω

FDD9511L-F085

Features

- Typ $r_{DS(on)} = 17 \text{ m}\Omega$ at $V_{GS} = -10 \text{ V}$; $I_D = -25 \text{ A}$
- Typ $Q_{g(tot)} = 17 \text{ nC}$ at $V_{GS} = -10 \text{ V}$; $I_D = -25 \text{ A}$
- UIS Capability
- Qualified to AEC Q101
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electrical Power Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM

Rating	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	-40	V
Gate to Source Voltage	V _{GS}	±16	V
Drain Current – Continuous (V _{GS} = –10 V) (T _C = 25°C) (Note 1)	۱ _D	-25	A
Pulsed Drain Current (T _C = 25° C)	Ι _D	See Figure 4	A
Single Pulse Avalanche Energy (Note 2)	E _{AS}	25	mJ
Power Dissipation	PD	48.4	W
Derate above 25°C	PD	0.32	W/°C
Operating and Storage Temperature Range	T _J , T _{STG}	–55 to +175	°C
Thermal Resistance (Junction to Case)	$R_{\theta JC}$	3.1	°C/W
Maximum Thermal Resistance (Junction to Ambient) (Note 3)	R_{\thetaJA}	52	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

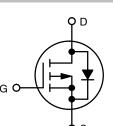
- 1. Current is limited by wirebond configuration
- 2. Starting Tj = 25°C, L = 0.08 mH, I_{AS} = -25 A, V_{DD} = -40 V during inductor charging and $V_{DD} = 0$ V during time in avalanche
- 3. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2 oz copper.



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ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Reel Size	Tape Width	Quantity
FDD9511L-F085	FDD9511L	D-PAK (TO-252)	13″	12 mm	2500 Units

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
F CHARAC	TERISTICS	•					
BV _{DSS}	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$		-40	-	-	V
I _{DSS}	Drain to Source Leakage Current	V_{DS} = -40 V, V_{GS} = 0 V	$T_J = 25^{\circ}C$	-	-	-1	μΑ
			T _J = 175°C (Note 4)	-	-	-1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 16 \text{ V}$		-	-	±100	nA
I CHARACT	ERISTICS						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$		-1	-1.8	-3	V
R _{DS(on)}	Drain to Source On-Resistance	V_{GS} = -4.5 V, I_D = -12.5 A, T_J = 25 $^\circ C$		-	24	32	mΩ
		$ \begin{array}{c} V_{GS} = -10 \ V, \\ I_D = -25 \ A \end{array} \begin{array}{c} T_J = 25 \ ^\circ C \\ T_J = 175 \ ^\circ C \ (\text{Note 4}) \end{array} $	$T_J = 25^{\circ}C$	-	17	21	mΩ
			-	28	36	mΩ	
	ARACTERISTICS						
C _{iss}	Input Capacitance	V _{DS} = -20 V, V _{GS} = 0 V, f = 100 KHz		-	1200	-	pF
C _{oss}	Output Capacitance			-	480	-	pF
C _{rss}	Reverse Transfer Capacitance			-	27	-	pF
Rg	Gate Resistance	V _{GS} = -0.5 V, f = 1 MHz		-	38	-	Ω
Q _{g(tot)}	Total Gate Charge	$V_{DD} = -20 V,$	V_{GS} = 0 V to -10 V	-	17	23	nC
Q _{g(-4.5)}	Total Gate Charge	I _D = -25 A	V_{GS} = 0 V to -4.5 V	-	8	-	nC
Q _{g(th)}	Threshold Gate Charge		V_{GS} = 0 V to -1 V	-	1	-	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DD} = -20 \text{ V}, \text{ I}_{D}$	= -25 A	-	4	-	nC

Q_{gd} SWITCHING CHARACTERISTICS

Gate to Drain "Miller" Charge

t _{on}	Turn-On Time		-	-	45	ns
t _{d(on)}	Turn-On Delay Time		-	7	-	ns
tr	Turn-On Rise Time		-	24	-	ns
t _{d(off)}	Turn-Off Delay Time	-	-	120	-	ns
t _f	Turn-Off Fall Time		-	40	-	ns
t _{off}	Turn-Off Time		-	-	235	ns

2.5

nC

DRAIN-SOURCE DIODE CHARACTERISTICS

V _{SD}	Source to Drain Diode Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{SD} = -25 \text{ A}$	-	-0.95	-1.25	V
		$V_{GS} = 0 \text{ V}, \text{ I}_{SD} = -12.5 \text{ A}$	-	-0.9	-1.2	V
T _{rr}	Reverse Recovery Time	I_F = -25 A, dI _{SD} /dt = 100 A/µs	-	36	54	ns
Q _{rr}	Reverse Recovery Charge		-	22	33	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. The maximum value is specified by design at $T_J = 175^{\circ}$ C. Product is not tested to this condition in production

TYPICAL CHARACTERISTICS

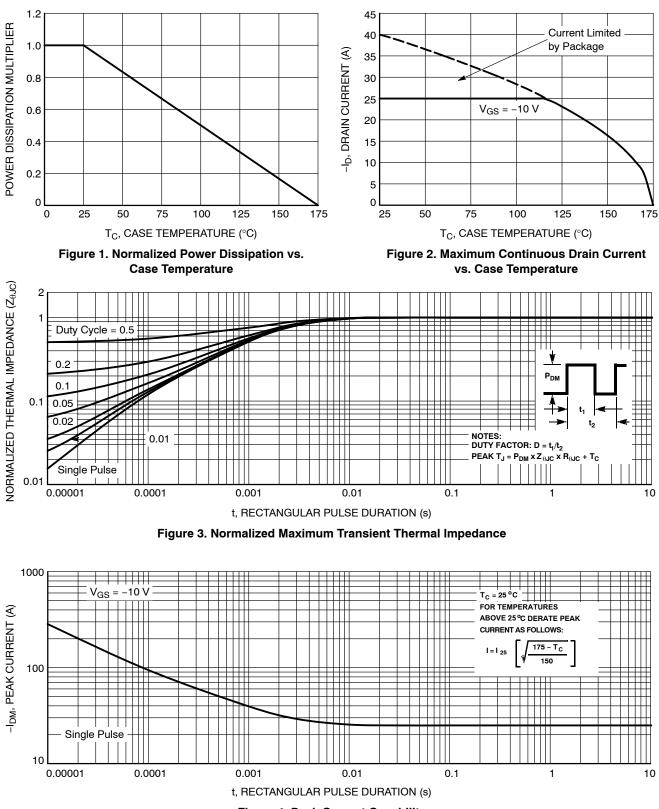
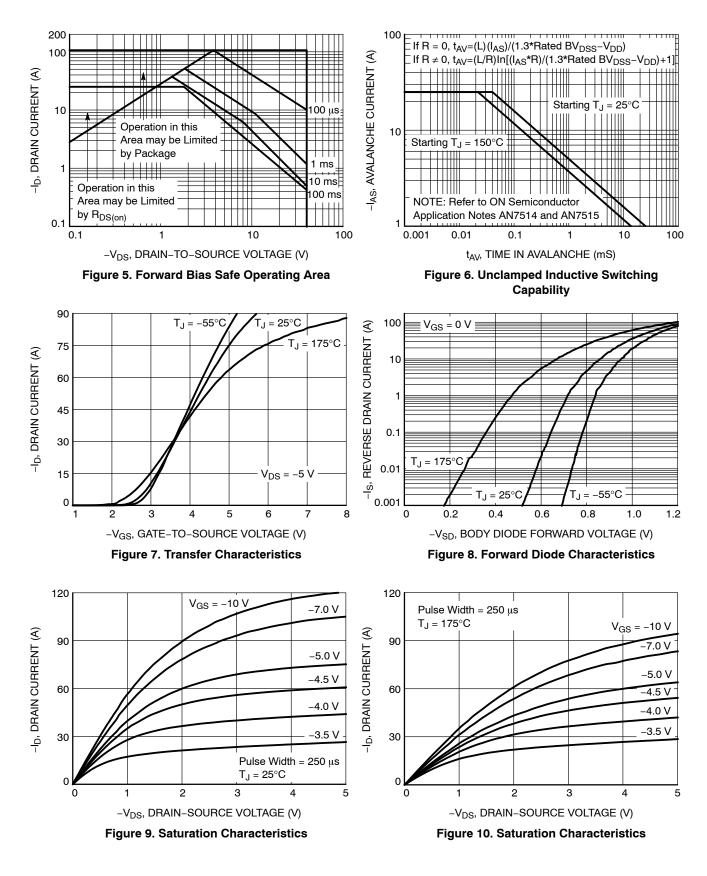
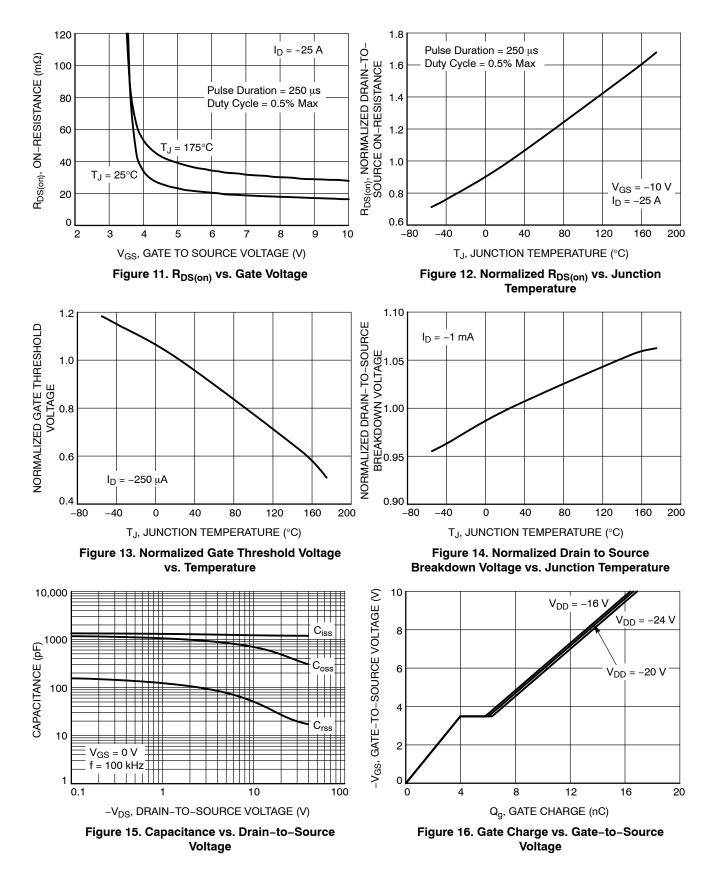


Figure 4. Peak Current Capability

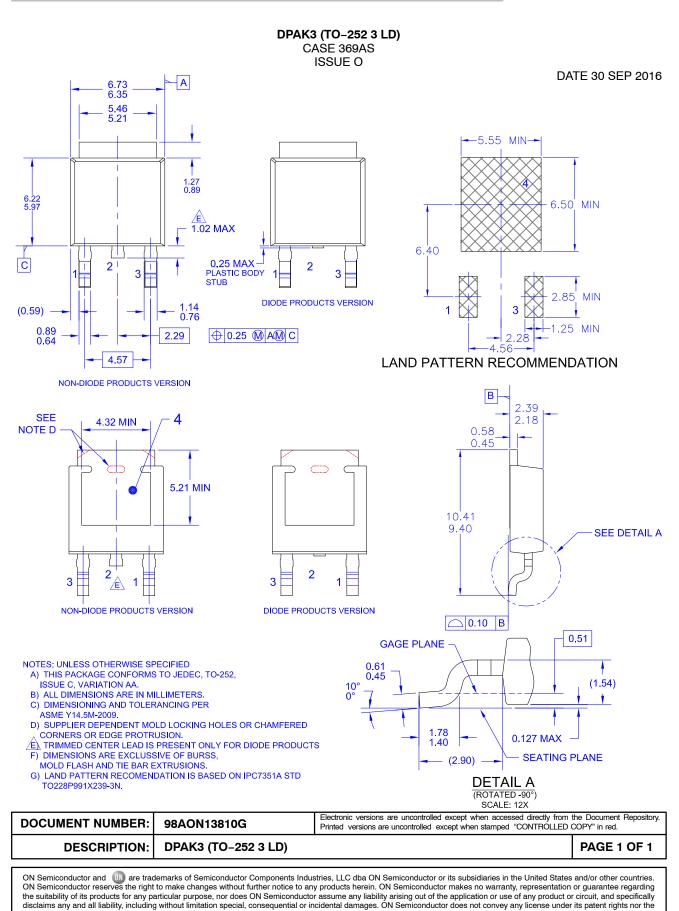
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS







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